

Development of Hard X-ray Photoemission Spectroscopy for Advanced Materials Science and Technology at BL-47XU/SPRING-8

Eiji Ikenaga¹, Masaaki Kobata², Masatake Machida¹, Jin-Young Son¹, Hiroyuki Matsuda³, Hiroshi Daimon³, Yoshio Watanabe¹, Keisuke Kobayashi²
 JASRI/SPRING-8¹, National Institute for Materials Science², Nara Institute of Science and Technology³
 ikenaga@spring8.or.jp

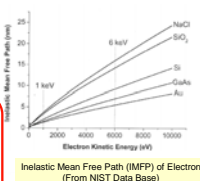
Hard X-ray Photoemission Spectroscopy

Introduction

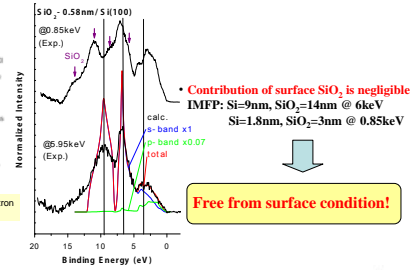
HAXPES - Large probing depth!

IMFPs
 1~4nm @ 1 keV
 4~15nm @ 8 keV

- Surface insensitive (Bulk sensitive)
- Free from surface prep. MBE thin film
- Chemical depth analysis Embedded interface (non destructive)

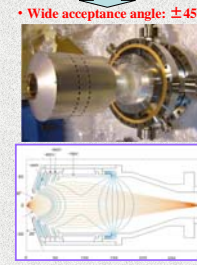


Feature Proof of surface insensitivity



Development & Object

Development of Objective Lens
 • Present status of solid angle: $\pm 7^\circ$ (R-4000 SCIENTA Analyzer)



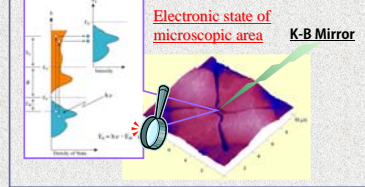
• Wide acceptance angle: $\pm 45^\circ$

• High throughput

Introduce focusing optics

Present status of V: $40 \mu\text{m}$ H: $35 \mu\text{m}$

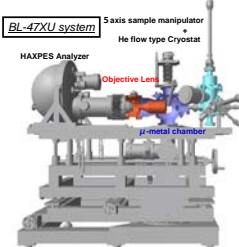
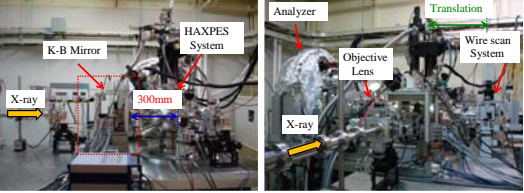
After installation K-B Mirror, Status of beam spot size $\Rightarrow \phi 1 \mu\text{m} \sim \text{submicron}$



In combination with focused beam and x-y scanning of the sample, we will realize the 3D mapping in the chemical states

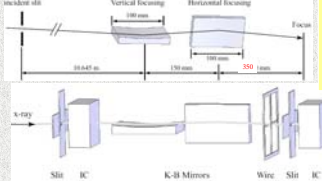
Public Beamline -47XU

Live show



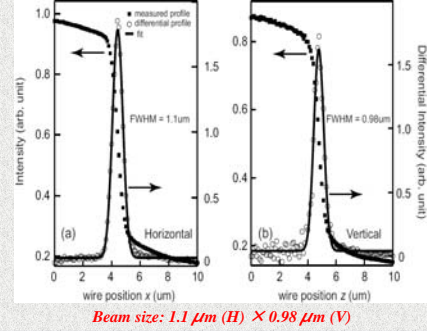
Introduce focusing optics

(Alignment) elliptical mirrors; figure errors $\sim 2 \text{ nm}$; platinum coating; glancing angle $\sim 3 \text{ mrad}$; incident slit: $300 \times 300 \mu\text{m}$



- Working distance: 350 mm (BL47XU)
- Beam size: $1 \mu\text{m}$
- Gain: 10^{12-13}

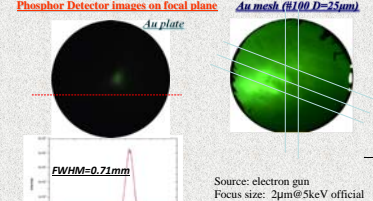
(Focusing Result)



Development of Objective Lens

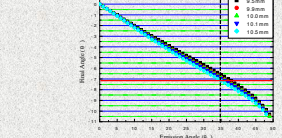
Wide angle object lens newly developed by 10kV voltage-proof specification (2007, completion in December)
 • About withstanding voltage
 • Stable operation under 8kV application for 48 hrs without discharge.
 Main feature
 • Discharge prevention measures by simplification of correction electrode part structure
 • The surface-roughness that disarranges equipotential is excluded.
 • Working Distance: 10mm
 • Magnification factor: 5
 • (Spheroid shape mesh evaluation: focusing size)

Phosphor Detector images on focal plane
 Au plate Au mesh (R100 D=25um)



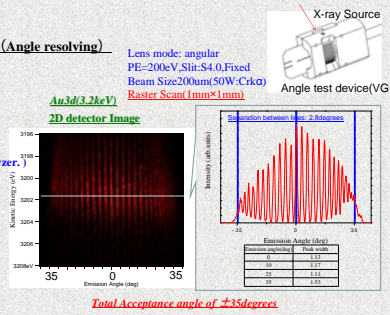
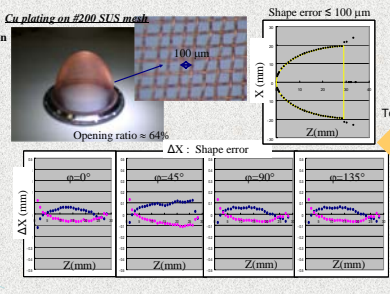
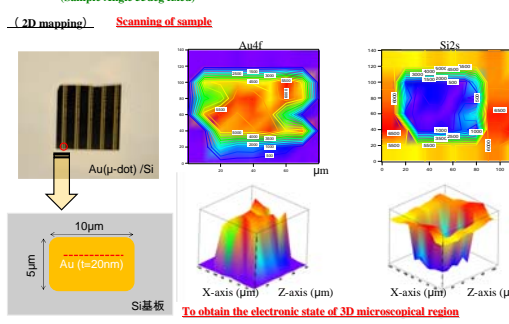
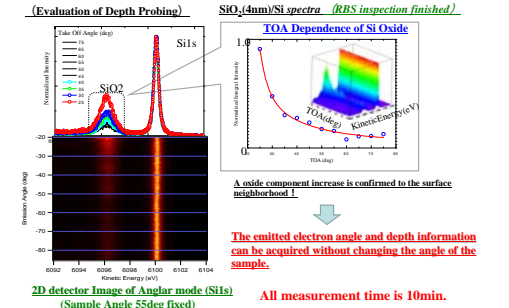
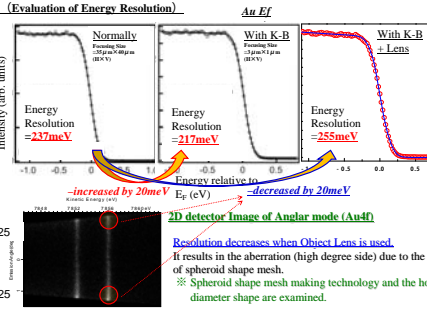
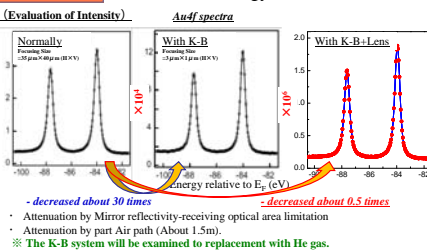
Why Total Acceptance angle is ± 35 degrees?

• It is consistent to the Trace result. (Limit due to the solid angle of Analyzer.)



Results

Photon Energy = 8KeV



• Aberration by apertures of lens mesh

“Evaluation of the dispersive nature of meshes used for the spherical aberration correction of electrostatic lenses”
 M. Kato et al., J. Vac. Sci. Technol. A 14(2), Mar/Apr 1996 (1996)
 The focal image by the effect of the hole is irrelevant to the aberration in the diameter of the hole.

• Davison-Calbick

$$f_{\text{hole}} = \frac{4\Phi_0}{E_1 - E_2}$$

Φ_0 : Final axial potential
 Potential difference at Mesh hole position

The hole of the mesh is thought as a lens focal length fM.

$$\Delta d_0 = \frac{s_0 - s_c}{s_c} D = \frac{s_0}{f_{\text{hole}}} D$$

• Calculation of focal image when electron is settled by 1KV with the wire of diameter 30 μm

$V(r) = \frac{Q}{4\pi\epsilon_0 r}$
 $E_1 = -67 \text{ V/mm}$
 $\Phi_0 = 1000 \text{ V}$
 $Q = \Phi_0 \cdot \epsilon_0 \cdot E_1 D = 1000 \cdot 8.85 \times 10^{-12} \cdot (-67) \cdot 0.224 = -6.66$
 $f_{\text{hole}} = \frac{4 \times 1000}{-6.66} = -60 \text{ mm}$
 $\Delta d_0 = \frac{s_0}{f_{\text{hole}}} D = \frac{50 \text{ mm}}{-60} \cdot 0.833 D = 0.186 (D = 0.224)$
 $= 0.02 (D = 0.024)$

The mesh hole of 24μm is necessary for obtaining an actual 0.1mm image.